

2STN2540

Low voltage fast-switching PNP power bipolar transistor

Preliminary Data

General features

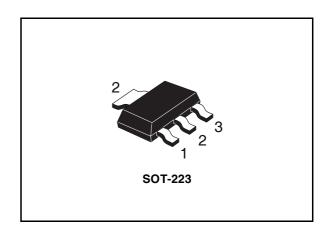
- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Surface mounting device in medium power SOT-223 package
- In compliance with the 2002/93/EC European Directive

Description

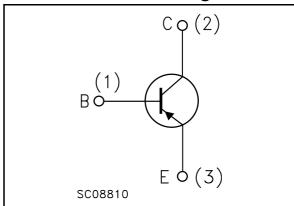
The device in a PNP transistor manufactured using new "PB-HCD" (Power Bipolar High Current Density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

Applications

- Emergency lighting
- Led
- CCFL drivers (back lighting)
- Voltage regulation
- Relay driver



Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing
2STN2540	N2540	SOT-223	Tape & reel

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1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-40	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-40	V
V _{EBO}	Emitter-base voltage (I _C = 0)	-6	V
I _C	Collector current	-5	Α
I _{CM}	Collector peak current (t _P < 5ms)	-10	Α
I _{BM}	Base peak current (t _P < 5ms)	-2	Α
P _{tot}	Total dissipation at T _{amb} = 25°C	1.6	W
T _{stg}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

Table 2. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-amb} ⁽¹⁾	Thermal resistance junction-amb max	78	°C/W

⁽¹⁾ Device mounted on PCB area of 1cm²

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2 Electrical characteristics

(T_{case} = 25°C unless otherwise specified)

Table 3. Electrical characteristics

Symbol	Parameter	Test Co	Min.	Тур.	Max.	Unit	
I _{CBO}	Collector cut-off current (I _E =0)	V _{CB} = -30V				-0.1	μА
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = -5V				-0.1	μА
		I _C = -0.5A I	_B = -5mA		-80	-120	mV
V _{CE(sat)} (2)	Collector-emitter	I _C = -1A I	_B = -10mA		-120	-180	mV
	saturation voltage	I _C = -2A I	_B = -200mA		-140	-200	mV
		$I_C = -5A$ I	$_{\rm B}$ = -500mA		-350	-450	mV
V _{BE(sat)} (2)	Base-emitter saturation voltage	I _C = -5A I	_B = -500mA			-1.3	V
V _{BE(on)} (2)	Base-emitter on voltage	V _{CE} = -2V I	I _C = -2A			-1.25	V
		$I_{C} = -0.5A$	$V_{CE} = -2V$	250			
h _{FE} ⁽²⁾	DC current gain	I _C = -1A	$V_{CE} = -2V$	200			
		I _C = -2A		150			
		I _C = -5A	V _{CE} = -2V	50			

Note (2) Pulsed duration = 300 μ s, duty cycle \leq 1.5%

2.1 Electrical characteristics (curves)

Figure 1. DC current gain

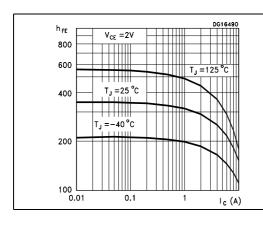


Figure 2. Collector-emitter saturation voltage

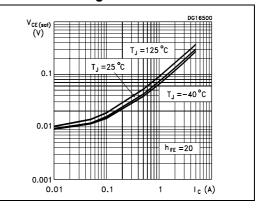
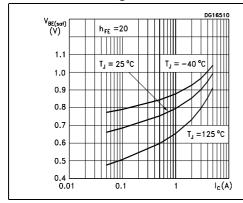
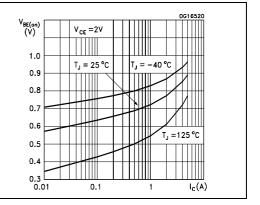


Figure 3. Base-emitter saturation voltage

Figure 4. Base-emitter on voltage





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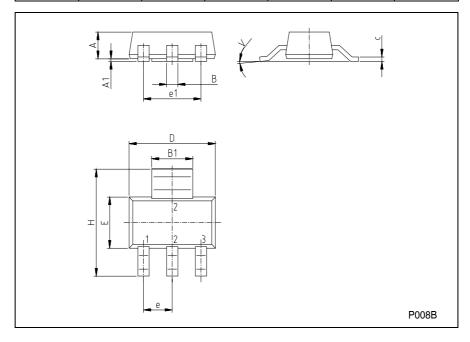
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



SOT-223 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α			1.80			0.071
В	0.60	0.70	0.80	0.024	0.027	0.031
B1	2.90	3.00	3.10	0.114	0.118	0.122
С	0.24	0.26	0.32	0.009	0.010	0.013
D	6.30	6.50	6.70	0.248	0.256	0.264
е		2.30			0.090	
e1		4.60			0.181	
Е	3.30	3.50	3.70	0.130	0.138	0.146
Н	6.70	7.00	7.30	0.264	0.276	0.287
V			10°			10°
A1		0.02				



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4 Revision history

Table 4. Revision history

Date	Revision	Changes
23-Oct-2006	1	Initial release
03-Nov-2006	2	New graphics

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